

**ECE 2C Mid-Term Exam**

**May 5, 2011**

Do not open exam until instructed to.

Closed book: Crib sheet and 1 page personal notes permitted

There are 2 problems on this exam, and you have 75 minutes.

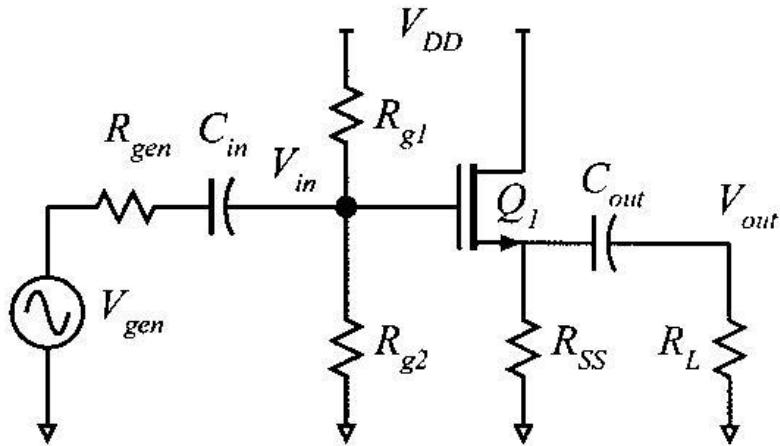
Use any and all reasonable approximations (5% accuracy is fine.) , **AFTER STATING  
and approximately Justifying them.**

Name: solution "B"

Problem	Points Received	Points Possible
1a		10
1b		10
1c		10
1d		15
1e		10
1f		10
1g		15
2a		15
2b		5
total		100

**Problem 1, 85 points**

You will be working on the circuit below:



Q1 is a velocity-limited FET, i.e.  $I_d = (v_{sat}c_{ox}W_g)(V_{gs} - V_{th})(1 + \lambda V_{ds})$   
where  $v_{sat}c_{ox}W_g = 4 \text{ mA/V}$ ,  $\lambda = 0.1 \text{ V}^{-1}$ , and  $V_{th} = 0.25 \text{ V}$ .

$V_{DD} = +3.0 \text{ volts}$ .

$C_{in}$  and  $C_{out}$  are very big and have negligible AC impedance.

$R_L = 5 \text{ kOhm}$

$R_{gen} = 1 \text{ MOhm}$

Part a, 10 points

DC bias.

Q1 is to be biased with 1.5 mA drain current.

The source of Q1 is to be biased at 1.0 Volts

The DC current in Rg1 is 1  $\mu$ A

Ignore  $\lambda$  while solving this part.

Find:  $R_{g1} = \underline{1.375 M\Omega}$     $R_{g2} = \underline{1.625 M\Omega}$     $R_{ss} = \underline{667.12}$

2.5

$$\begin{cases} \frac{1.5 \text{ mA}}{V_{gs} - V_{th}} = 1.5 \text{ mA} \\ V_{gs} - V_{th} = 0.275 \text{ V} \\ V_{gs} = 0.625 \text{ V} \\ V_g = 0.625 \text{ V} + 1 \text{ V} = 1.625 \text{ V} \end{cases}$$

2.5

$$R_{ss} = 1 \text{ V} / 1.5 \text{ mA} = 667 \Omega$$

2.5

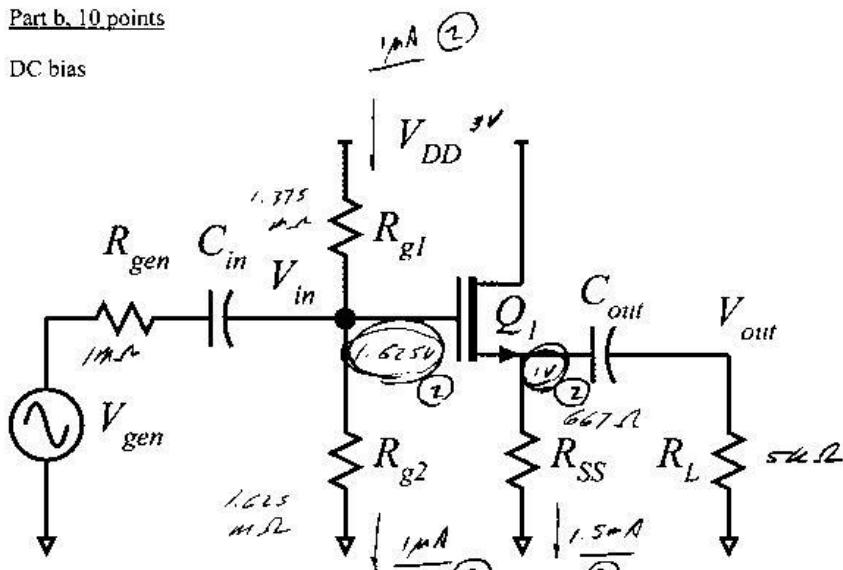
$$R_{g2} = 1.625 \text{ V} / 1 \text{ mA} = 1.625 \text{ M}\Omega$$

2.5

$$R_{g1} = \frac{(5 \text{ V} - 1.625 \text{ V})}{1 \text{ mA}} = 1.375 \text{ M}\Omega$$

Part b, 10 points

DC bias



On the circuit diagram above, label the DC voltages at ALL nodes and the DC currents through ALL resistors

$$I_{in} = 4 \text{ mA}$$

$$\lambda = 0.1$$

$$V_{CE} = 1140.$$

2 pts each

$$\frac{4 \text{ mA}}{2} (V_{GS} - V_{CE}) = 1.5 \text{ mA} \rightarrow$$

Part c, 10 points

Find the small signal parameters of Q1. Use the constant-velocity model.

$$g_m = \frac{4mA/V}{6.7k\Omega}$$

5  $\left[ \begin{array}{l} g_m = 4mA/V \quad \text{or} \quad (4mA/V)(1 + k/V_{ds}) \\ R_{ds} = \frac{V_{ds} + 10V}{2V + 10V} = \frac{1.54k\Omega}{1.54k\Omega} \\ \text{or} \\ \approx \frac{1}{2V} = \frac{10V}{1.54k\Omega} = 6.7k\Omega \end{array} \right] \text{ Both acceptable} \right)$

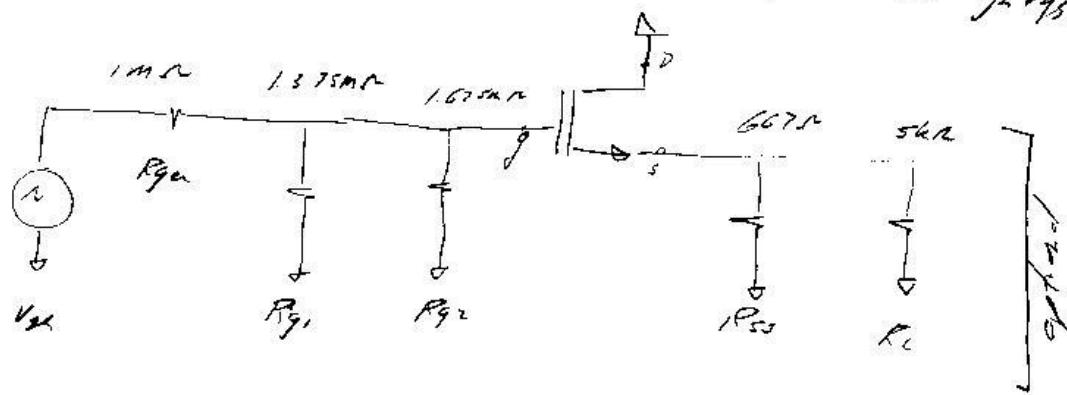
Part d. 15 points

Replacing the transistor with its small-signal model, draw a small-signal equivalent circuit diagram for the amplifier. Give values for all elements on the diagram.

$$g_m = 4 \text{ mA/V}$$

$$R_{ds} = 6.7 \text{ k}\Omega$$

Points off if elements  
MOSFET, including + -  $V_{GS}$  control point for  $g_m V_{GS}$ .



$$g_m = 4 \text{ mA/V}$$

$$R_{ds} = 6.7 \text{ k}\Omega$$

$$R_{ss} = 6.7 \text{ k}\Omega$$

$$R_L = 5.6 \text{ k}\Omega$$

needed

$$R_{in} = 774 \text{ k}\Omega$$

Part c, 10 points.

Find the small signal voltage gain ( $V_{out}/V_{in}$ ) of Q1.

$$V_{out}/V_{in} = \underline{0.683}$$

$$5 \left[ R_{eq} = R_{ss} \parallel R_L \parallel R_{os} = 540 \Omega \right]$$

$$5 \left[ \frac{V_o}{V_i} = \frac{g_m R_{eq}}{g_m R_{eq} + 1} = \frac{2.16}{1 + 2.16} = \underline{\underline{0.683}} \right]$$

Part f, 10 points

Find the \*\*\* amplifier \*\*\* input resistance, Vin/Vgen, and Vout/Vgen

$$R_{in, \text{amplifier}} = \underline{774 \text{ k}\Omega}$$

$$V_{in}/V_{gen} = \underline{0.439}$$

$$(V_{out}/V_{gen}) = \underline{0.30}$$

$$4 \quad \left[ R_{in, \text{amp}} = R_1 / R_2 = 774 \text{ k}\Omega \right]$$

$$4 \quad \left[ \frac{V_{in}/V_{gen}}{R_{in} + R_{gen}} = \frac{R_{in, \text{amp}}}{R_{in, \text{amp}} + R_{gen}} = 0.4386 \right]$$

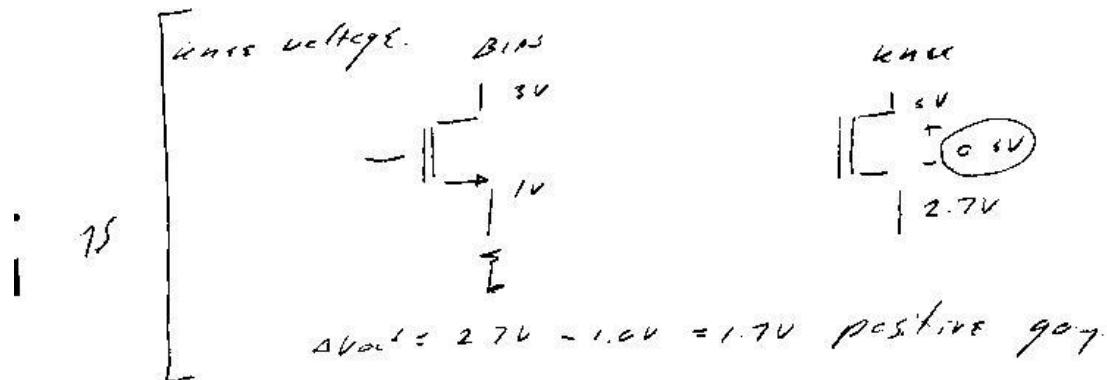
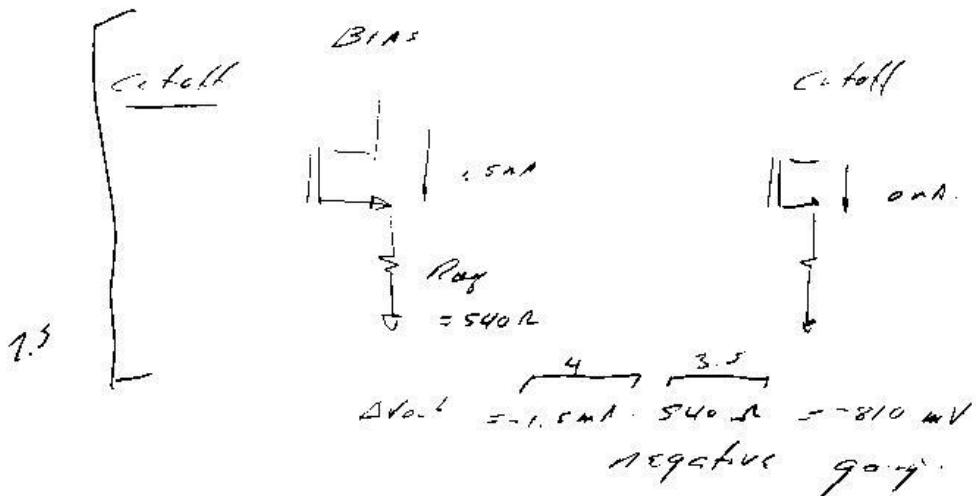
$$3 \quad \left[ \frac{V_{out}}{V_{gen}} = \frac{V_{out}}{V_{in}} \cdot \frac{V_{in}}{V_{gen}} = 0.296 \right]$$

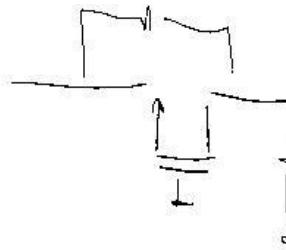
Part g. 15 points

Now you must find the maximum signal swings. Find the output voltage due to the knee voltage and due to cutoff in Q1. Since this is a constant-velocity model, the knee voltage of the transistor must be specified:  $V_{DS,knee} = V_{DS,\text{minimum}} = V_{DS,\text{saturation}} = 0.30 \text{ Volts}$ , i.e. the FET must have a minimum 0.30 Volts between drain and source for linear operation.

Cutoff of Q1; Maximum  $\Delta V_{out}$  resulting = -0.81 V

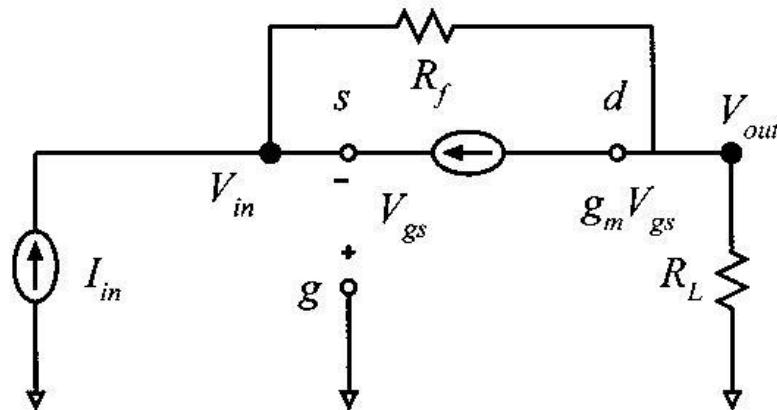
Knee voltage of Q1; Maximum  $\Delta V_{out}$  resulting = +1.7 V





**Problem 2, 20 points**  
Nodal analysis

Part a, 15 points



Using nodal analysis, determine  $V_{out}/I_{in}$

5pt [ Nodal equation at  $V_{in}$ :  $\frac{V_{in}(g_m + 1/R_f) + V_{out}(-1/R_L)}{R_f} = I_{in}$  ]

5pt [ Nodal equation at  $V_{out}$ :  $\frac{V_{in}(-g_m - 1/R_f) + V_{out}(1/R_L + 1/R_f)}{R_L} = 0$  ]

5pt [  $V_{out}/I_{in} = \frac{R_L}{R_f}$  ]

$\Sigma I = 0 \text{ at } V_i$   $(V_{in} - V_{out})/R_f + g_m V_{in} = I_{in}$  E  
 $V_{in}(g_m + 1/R_f) + V_{out}(-1/R_f) = I_{in}$

$\Sigma I = 0 \text{ at } V_o$   $V_{in}(1/R_L + (V_{in} - V_o)/R_L) - g_m V_o = 0$   
 $V_{in}(-1/R_L - g_m) + V_{out}(1/R_L + 1/R_f) = 0$

$$\begin{vmatrix} I_m + G_f & -G_f & v_r \\ -G_f - g_m & G_f + G_c & \text{Net} \end{vmatrix} = \begin{vmatrix} I_r \\ 0 \\ 0 \end{vmatrix}$$

$$V_{out} = \frac{N}{D}$$

$$N = \begin{vmatrix} I_m + G_f & I_m \\ -G_f - g_m & 0 \end{vmatrix} = I_m (I_m + G_f)$$

$$D = \begin{vmatrix} I_m + G_f & -G_f \\ -G_f - g_m & G_f + G_c \end{vmatrix} = I_m G_f + g_m G_c + G_f G_f + G_f g_m$$

$$= I_m G_c + g_m G_f = G_c (g_m + G_f)$$

$$V_{out} = \frac{I_m (g_m + G_f)}{G_c (g_m + G_f)} = \frac{I_m}{G_c} \cdot Z_m R_o$$

Answer to the problem is part (ii) :-  
all open circuit bias :  $R_o$

Part b, 5 points

$R_i = 1 \text{ kOhm}$ ,  $R_f = 10 \text{ kOhm}$ ,  $g_m = 100 \text{ mS}$ .

Find the numerical value of  $V_{out}/I_m$ :

$$\boxed{V_{out}/I_m = \underline{\hspace{2cm}} / \underline{\hspace{2cm}}}$$